

C6D08065ESilicon Carbide Schottky Diode

Z-Rec® Rectifier

 V_{RRM} = 650 V $I_F(T_c=155^{\circ}C)$ = 8 A Q_c = 29 nC

Features

- New 6th Generation Technology
- Low Forward Voltage Drop (V_F)
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Low Leakage Current (I)
- Temperature-Independent Switching Behavior
- Positive Temperature Coefficient on V_E

Benefits

- Higher System Level Efficiency
- Increase System Power Density
- · Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Server/Telecom Power Supplies
- · Industrial Power Supplies
- Solar
- UPS

Package







TO-252-2



Part Number	Package	Marking		
C6D08065E	TO-252-2	C6D08065		

Maximum Ratings ($T_c = 25^{\circ}$ C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	650	٧		
V _{DC}	DC Blocking Voltage	650	٧		
I _F	Continuous Forward Current	29 15 8	А	T _c =25°C T _c =125°C T _c =155°C	Fig. 3
I _{FRM}	Repetitive Peak Forward Surge Current	34 20	А	T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =110°C, t_p = 10 ms, Half Sine Wave	
I _{FSM}	Non-Repetitive Peak Forward Surge Current	63 57	А	T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =110°C, t_p = 10 ms, Half Sine Wave	Fig. 8
I _{F,Max}	Non-Repetitive Peak Forward Surge Current	781 717	Α	T_c =25°C, t_p = 10 μ s, Pulse T_c =110°C, t_p = 10 μ s, Pulse	Fig. 8
P _{tot}	Power Dissipation	85 37	W	T _c =25°C T _c =110°C	Fig. 4
$T_{\scriptscriptstyle J}$, $T_{\scriptscriptstyle stg}$	Operating Junction and Storage Temperature	-55 to +175	°C		



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.27 1.37	1.50 1.60	V	$I_F = 8 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 8 \text{ A } T_J = 175^{\circ}\text{C}$	Fig. 1
I_R	Reverse Current	2 15	40 160	μΑ	V _R = 650 V T _J =25°C V _R = 650 V T _J =175°C	Fig. 2
Q_{c}	Total Capacitive Charge	29		nC	V _R = 400 V, T _J = 25°C	Fig. 5
С	Total Capacitance	518 57 45		pF	$V_R = 0 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 200 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 400 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$	Fig. 6
E _c	Capacitance Stored Energy	4.4		μJ	V _R = 400 V	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
$R_{_{\theta JC}}$	Thermal Resistance from Junction to Case	1.77	°C/W	Fig. 9

Typical Performance

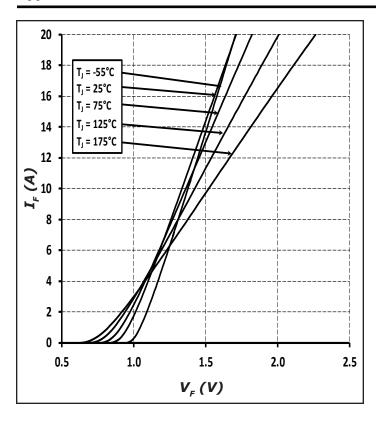


Figure 1. Forward Characteristics

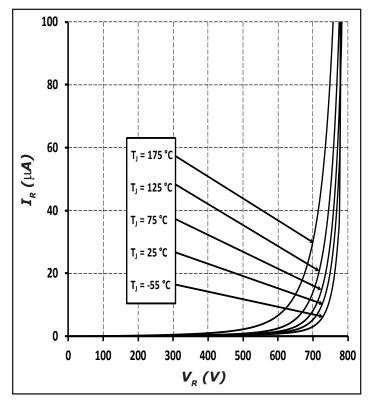
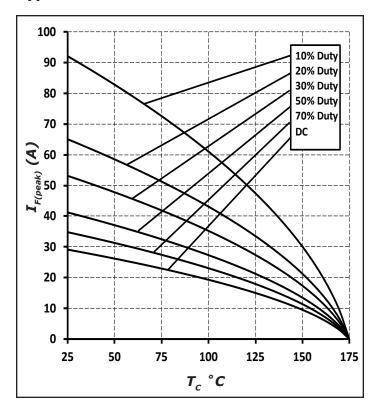


Figure 2. Reverse Characteristics



Typical Performance



M) 50 **d** 40 T_c $^{\circ}C$

Figure 3. Current Derating

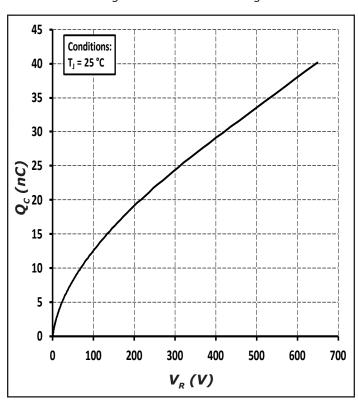


Figure 5. Total Capacitance Charge vs. Reverse Voltage

Figure 4. Power Derating

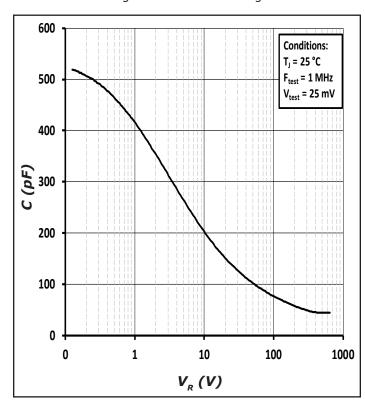
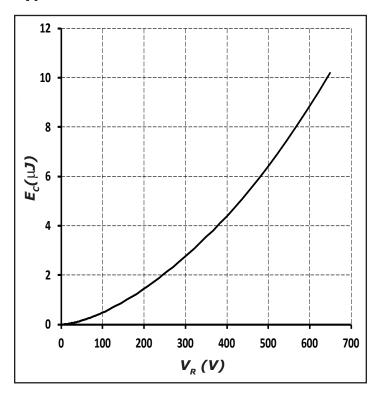


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance



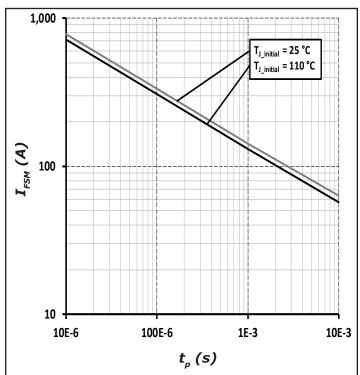


Figure 7. Capacitance Stored Energy

Figure 8. Non-repetitive peak forward surge current versus pulse duration (Sinusoidal Waveform)

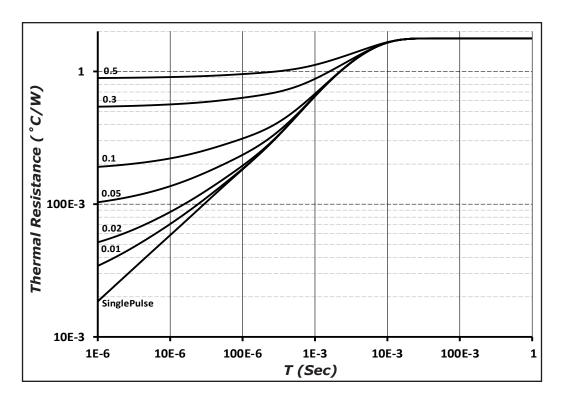
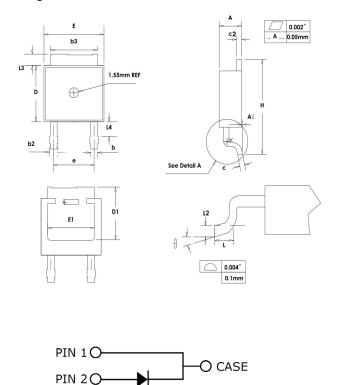


Figure 9. Transient Thermal Impedance



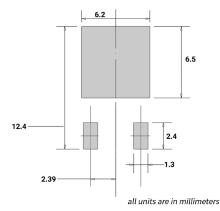
Package Dimensions

Package TO-252-2



SYMBOL	MILLIMETERS			
STIVIDOL	MIN	MAX		
А	2.159	2.413		
A1	0	0.13		
b	0.64	0.89		
b2	0.653	1.143		
b3	5.004	5.6		
С	0.457	0.61		
c2	0.457	0.864		
D	5.867	6.248		
D1	5.21	-		
E	6.35	6.73		
E1	4.32	-		
е	4.58	BSC		
Н	9.65	10.414		
L	1.106	1.78		
L2	0.51 BSC			
L3	0.889	1.27		
L4	0.64	1.01		
θ	0°	8°		

Recommended Solder Pad Layout



TO-252-2

Part Number	Package	Marking		
C6D08065E	TO-252-2	C6D08065		

Note: Recommended soldering profiles can be found in the applications note here: http://www.wolfspeed.com/power_app_notes/soldering





Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfspeed representative or from the Product Ecology section of our website at http://www.wolfspeed.com/power/tools-and-support/product-ecology.

REACh Compliance

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Cree representative to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

• This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

Related Links

- Cree SiC Schottky diode portfolio: http://www.wolfspeed.com/Power/Products#SiCSchottkyDiodes
- Schottky diode Spice models: http://www.wolfspeed.com/power/tools-and-support/DIODE-model-request2
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